Product data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

1.2 Features and benefits

- High speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

RF attenuators and switches

2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline Symbol
1	cathode	[1]
2	anode	
		Transparent sym006 top view

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BAP55LX	DFN1006D-2	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882D



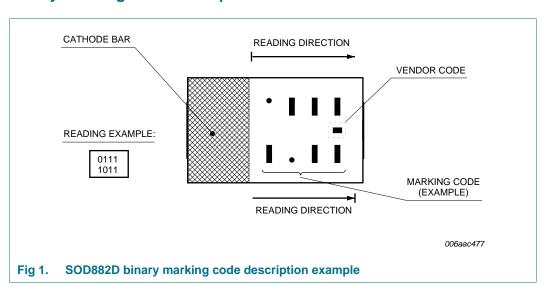
4. Marking

Table 3. Marking codes

Type number	Marking code ^[1]
BAP55LX	1111
	1101

^[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0 , ,	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	50	V
I _F	forward current		-	100	mA
P _{tot}	total power dissipation	T _{sp} = 90 °C	-	135	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5. Thermal characteristics

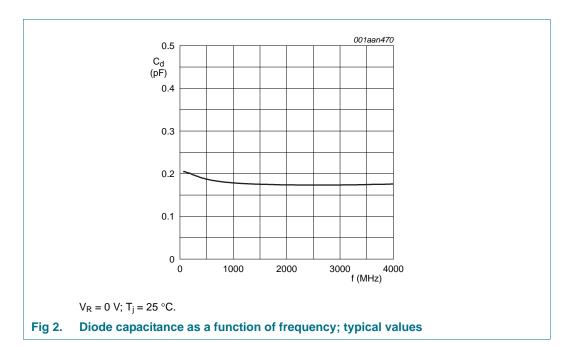
Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		78	K/W

7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 50 \text{ mA}$	-	0.95	1.1	V
I_R	reverse current	V _R = 20 V	-	-	10	nA
		V _R = 50 V	-	-	100	nA
C _d	diode capacitance	see Figure 3; f = 1 MHz;				
		$V_R = 0 V$	-	0.28	-	pF
		$V_R = 1 V$	-	0.23	-	pF
		V _R = 20 V	-	0.18	0.28	pF
r_D	diode forward resistance	see Figure 4; f = 100 MHz;				
		$I_F = 0.5 \text{ mA}$	-	3.3	4.5	Ω
		I _F = 1 mA	-	2.2	3.3	Ω
		I _F = 10 mA	-	8.0	1.2	Ω
		I _F = 100 mA	-	0.5	8.0	Ω
ISL	isolation	see <u>Figure 5</u> ; V _R = 0 V;				
		f = 900 MHz	-	19	-	dB
		f = 1800 MHz	-	14	-	dB
		f = 2450 MHz	-	12	-	dB
L _{ins}	insertion loss	see Figure 6; I _F = 0.5 mA;				
		f = 900 MHz	-	0.24	-	dB
		f = 1800 MHz	-	0.25	-	dB
		f = 2450 MHz	-	0.26	-	dB
L _{ins}	insertion loss	see Figure 6; I _F = 1 mA;				
		f = 900 MHz	-	0.17	-	dB
		f = 1800 MHz	-	0.18	-	dB
		f = 2450 MHz	-	0.19	-	dB
L _{ins}	insertion loss	see Figure 6; I _F = 10 mA;				
		f = 900 MHz	-	0.08	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.10	-	dB
L _{ins}	insertion loss	see Figure 6; I _F = 100 mA;				
		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.08	-	dB
τ_{L}	charge carrier life time	when switched from I _F = 10 mA to I _R = 6 mA; R _L = 100 Ω ; measured at I _R = 3 mA	0.225	0.27	-	μ\$
L _S	series inductance	I _F = 100 mA; f = 100 MHz	-	0.4	-	nH



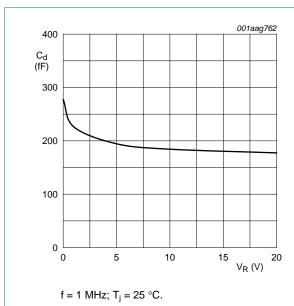


Fig 3. Diode capacitance as a function of reverse voltage; typical values

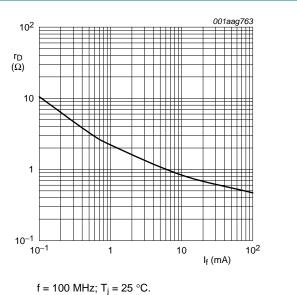
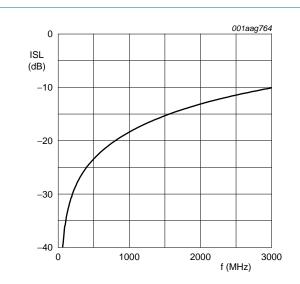


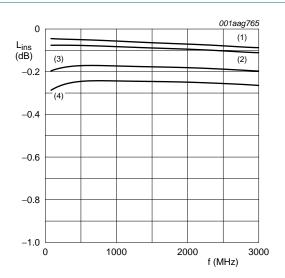
Fig 4. Forward resistance as a function of forward current; typical values



 T_{amb} = 25 $^{\circ}C$

Diode zero biased and inserted in series with a 50 Ω stripline circuit





T_{amb} = 25 °C

- (1) $I_F = 100 \text{ mA}$
- (2) $I_F = 10 \text{ mA}$
- (3) $I_F = 1 \text{ mA}$
- (4) $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

Fig 6. Insertion loss of the diode as a function of frequency; typical values

7.1 S-parameters

7.1.1 Diode in series configuration

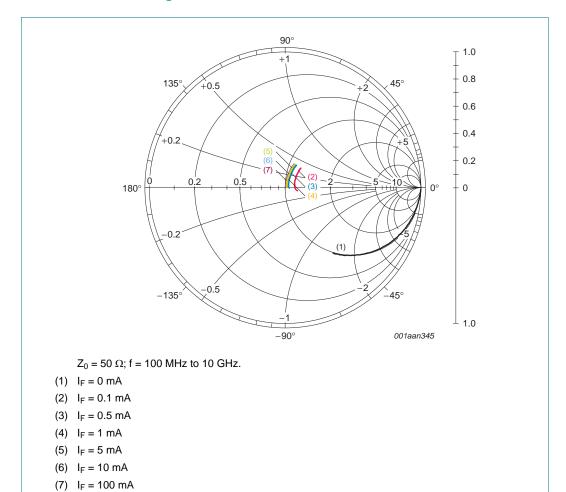
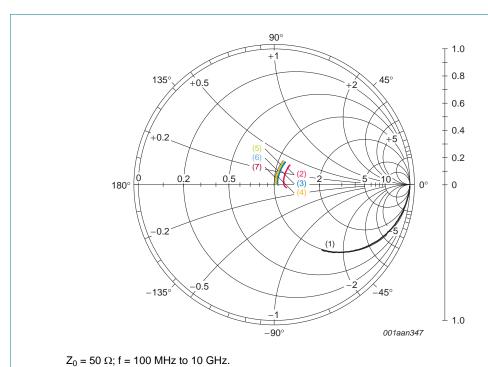
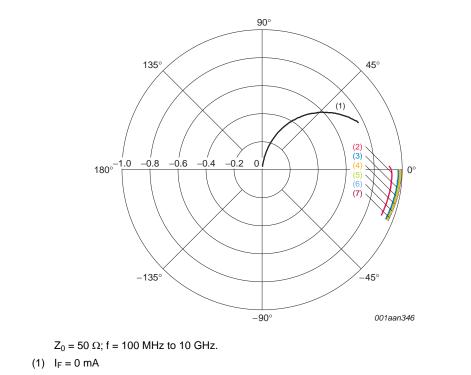


Fig 7. Input reflection coefficient (S₁₁); typical values



- (1) $I_F = 0 \text{ mA}$
- (2) $I_F = 0.1 \text{ mA}$
- (3) $I_F = 0.5 \text{ mA}$
- (4) $I_F = 1 \text{ mA}$
- (5) $I_F = 5 \text{ mA}$
- (6) $I_F = 10 \text{ mA}$
- (7) $I_F = 100 \text{ mA}$

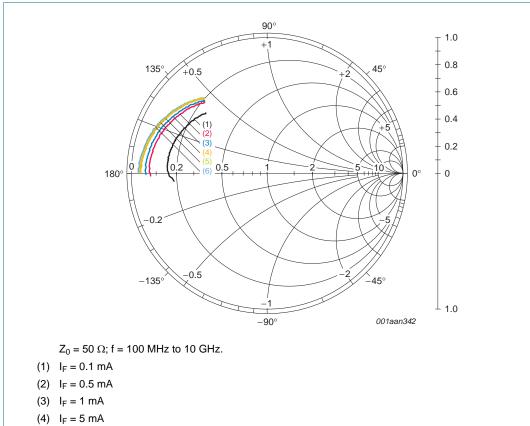
Fig 8. Output reflection coefficient (S₂₂); typical values



- (2) $I_F = 0.1 \text{ mA}$
- (3) $I_F = 0.5 \text{ mA}$
- (4) $I_F = 1 \text{ mA}$
- (5) $I_F = 5 \text{ mA}$
- (6) $I_F = 10 \text{ mA}$
- (7) $I_F = 100 \text{ mA}$

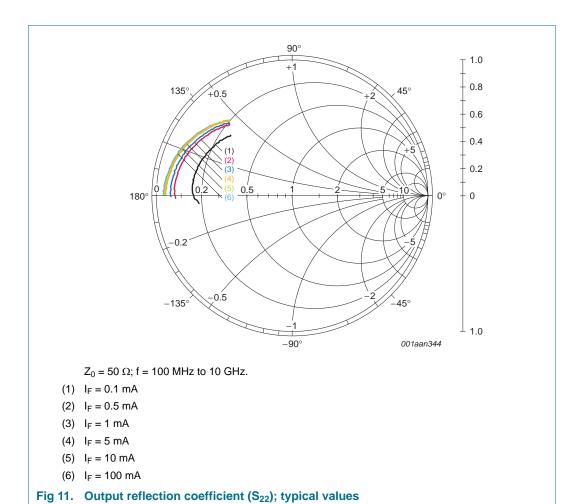
Fig 9. Forward transmission coefficient (S_{21}); typical values

7.1.2 Diode in parallel configuration



- (5) $I_F = 10 \text{ mA}$
- (6) $I_F = 100 \text{ mA}$

Fig 10. Input reflection coefficient (S_{11}); typical values



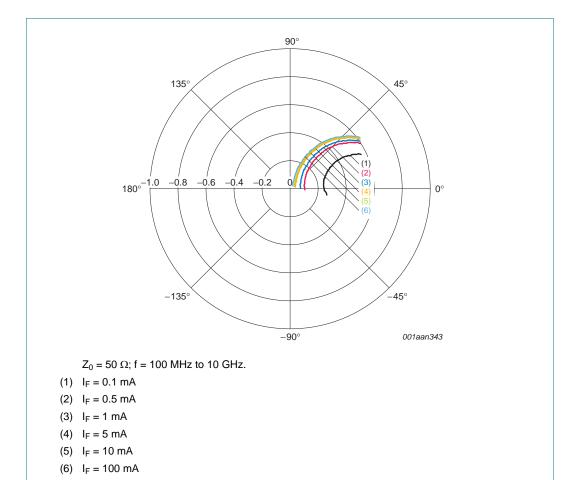


Fig 12. Forward transmission coefficient (S_{21}); typical values

8. Package outline

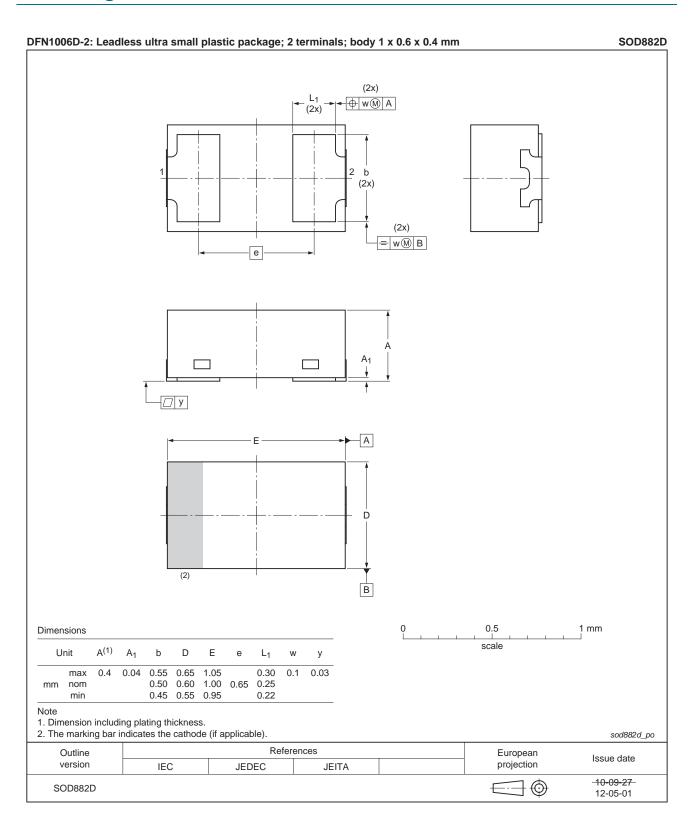


Fig 13. Package outline SOD882D (DFN1006D-2)

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9. Abbreviations

Table 7. Abbreviations

Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP55LX v.4	20130806	Product data sheet	-	BAP55LX v.3
Modifications:	Table 1 on pTable 2 on pSection 4 on	on page 1: Changed package age 1: Changed simplified out age 1: Changed package to S page 2: Update 'Marking' secondage 12: Changed package to page 13: Changed package to page 14: Changed package to	line to SOD882D OD882D ction	
BAP55LX v.3	20110113	Product data sheet	-	BAP55LX v.2
BAP55LX v.2	20101216	Product data sheet	-	BAP55LX v.1
BAP55LX v.1	20070730	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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Silicon PIN diode

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Silicon PIN diode

13. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
2	Pinning information 1
3	Ordering information
4	Marking
4.1	Binary marking code description 2
5	Limiting values 2
6	Thermal characteristics 2
7	Characteristics
7.1	S-parameters 6
7.1.1	Diode in series configuration 6
7.1.2	Diode in parallel configuration 9
8	Package outline
9	Abbreviations
10	Revision history
11	Legal information 14
11.1	Data sheet status
11.2	Definitions
11.3	Disclaimers
11.4	Trademarks15
12	Contact information
13	Contents

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